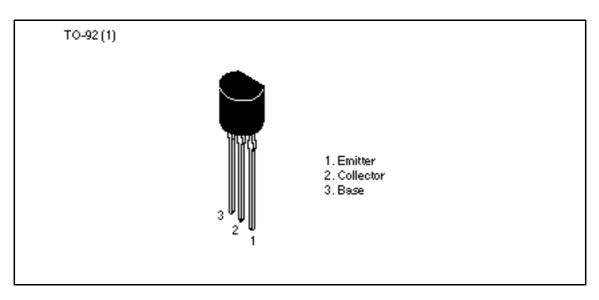
Silicon PNP Epitaxial

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#### Application

- Low frequency low noise amplifier
- Complementary pair with 2SC458 (LG) and 2SC2310

#### Outline





#### **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

Item	Symbol	2SA1031	2SA1032	Unit
Collector to base voltage	V <sub>CBO</sub>	-30	-55	V
Collector to emitter voltage	V <sub>CEO</sub>	-30	-50	V
Emitter to base voltage	V <sub>EBO</sub>	-5	-5	V
Collector current	I <sub>c</sub>	-100	-100	mA
Emitter current	l <sub>e</sub>	100	100	mA
Collector power dissipation	P <sub>c</sub>	300	300	mW
Junction temperature	Тј	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

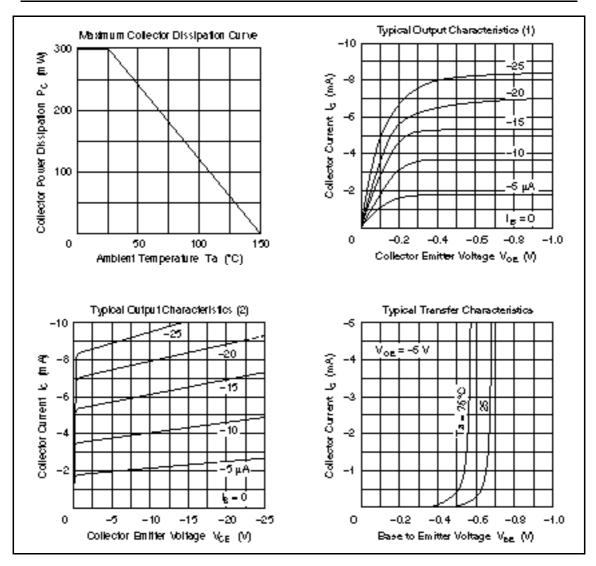
#### **Electrical Characteristics** (Ta = 25°C)

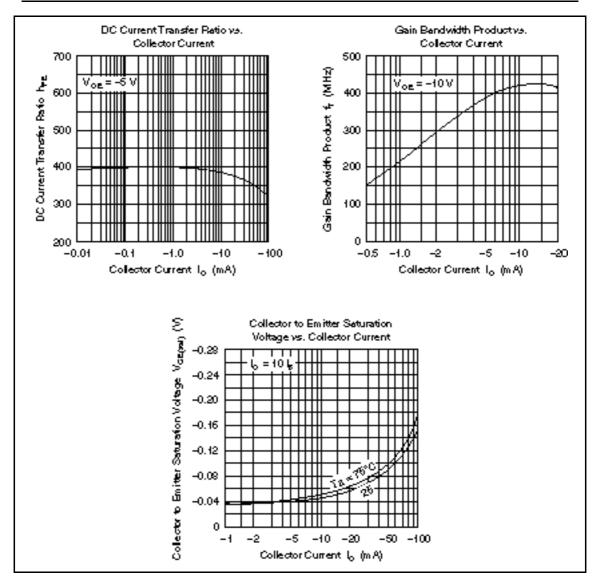
		2SA1	031		2SA1032				
Item	Symbol	Min	Тур	Max	Min	Тур	Мах	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-30		_	-55	_	_	V	$I_{c} = -10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	-30		_	-50	_	_	V	$I_c = -1$ mA, $R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-5		_	-5	_	_	V	$I_{\rm E} = -10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I <sub>CBO</sub>	—		-0.5			-0.5	μA	$V_{\rm CB} = -18 \text{ V}, \ I_{\rm E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	—		-0.5			-0.5	μA	$V_{EB} = -2 V, I_{C} = 0$
DC current trnsfer ratio	$h_{FE}^{*1}$	100	_	500	100	_	320		$V_{ce} = -12 V,$ $I_{c} = -2 mA$
Base to emitter voltage	$V_{BE}$		_	-0.8	_	_	-0.8	V	$V_{ce} = -12 V,$ $I_{c} = -2 mA$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	-0.2	_	_	-0.2	V	$I_{c} = -10 \text{ mA},$ $I_{B} = -1 \text{ mA}$
Gain bandwidth product	f <sub>T</sub>	200	280	_	200	280		MHz	$V_{ce} = -12 V,$ $I_{c} = -2 mA$
Collector output capacitance	Cob	—	3.3	4.0	_	3.3	4.0	pF	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz
Noise figure	NF			5			5	dB	

Note:	1.	The 2SA1031 and 2SA	A1032 are group	bed by h <sub>FE</sub> as follows.
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	В	С	D
2SA1031	100 to 200	160 to 320	250 to 500
2SA1032	100 to 200	160 to 320	_

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